IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re the Application of:

Atty. Docket No.:

002372.00044

Takashi OHSAWA

SerialNo.:

10/621,357

Group Art Unit:

2818

Filed:

July 18, 2003

Examiner:

Andrew Q. Tran

For:

SEMICONDUCTOR MEMORY MANUFACTURING THE SAME

INFORMATION DISCLOSURE STATEMENT

U.S. Patent and Trademark Office

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401 Dulany Street

Alexandria, VA 22314

Sir:

Pursuant to his duty of good faith and candor as set forth in 37 C.F.R. § 1.56(a) Applicant submits herewith the references cited on the attached PTO/SB/08a. The references listed on the PTO/SB/08a form were cited in an European Search Report from a related application. A copy of the Search Report is also submitted herewith. Applicant respectfully requests that the Examiner consider these references in connection with the search of the prior art required by 37 C.F.R. § 1.104.

Applicant notes that each item of information contained in the information disclosure statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the information disclosure statement.

Applicant does not waive any right to take any action that would be appropriate to antedate or otherwise remove any listed documents as a competent reference against the claims of the present application.

It is respectfully requested that the Examiner fully consider each item of information, initial the enclosed Form PTO/SB/08a in the appropriate place to indicate that the information has been considered, and return a copy of the initialed form to the undersigned in accordance with MPEP Section 609.

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PTO/SB/08a (08-03) Approved for use through 07/31/2006. OMB 0651-0031

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Under the Paperwork
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Complete if Known **Application Number** 10/621,357 Filing Date July 18, 2003 First Named Inventor Takashi OHSAWA Art Unit 2818 Examiner Name Andrew Q. Tran

(Use as many sheets as necessary)

Sheet 002372.00044 Attorney Docket Number

			U.S. PATENT	DOCUMENTS		
Examiner Initials *	Cite No.1	Document Number	Publication Date	Name of Patentee or Applicant of Cited	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
		Number - Kind Code ² (# known)	MM-DD-YYYY	Document		
at		US- 4,250,569	02/10/1981	Nobuo SASAKI, et al.		
at		US- 5,218,217	06/08/1993	Hidekazu ODA, et al.		
at		US- 5,712,501	01/27/1998	Robert B. DAVIES, et al.		
		US-				
		US-				

FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines,		
		Country Code ³ - Number ⁴ - Kind Code ⁶ (<i>if known</i>) MM-DD-Y		Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear	T ⁶	
at		JP 56-78156	06/26/1981		HOLL 27/10		
at		JP 56-119986	09/19/1981		G11c 11/34		
at		JP 8-213624	08/20/1996		HOLL 29/786		

NON PATENT LITERATURE DOCUMENTS					
Examiner Cite No.1		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
at		Patent Abstracts of Japan, Publication No. 56078156, Publication Date 06/26/1981, 1 page.			
at		Patent Abstracts of Japan, Publication No. 56119986, Publication Date 09/19/1981, 1 page.			
at		Patent Abstracts of Japan, Publication No. 08213624, Publication Date 08/20/1996, 1 page.			
at		Marix R. TACK, et al., "The Multistable Charge-Controlled Memory Effect in SOI MOS Transistors at Low Temperatures", IEEE Transactions on Electron Devices, Vol. 37, No. 5, May 1980, pp. 1373-1382.			
at		Shigeki TOMISHIMA, et al., "A Long Data Retention SOI-DRAM with the Body Refresh Function", 1996 Symposium on VLSI Circuits Digest of Technical Papres, pp. 198-199.			

Examiner Signature	ale	-	Date Considered	04/	30	2006	

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered.

*EXAMINER: Initial if reference considered, whether or not distion is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered, include copy of this form with next communication to applicant.

Applicant's unique citation designation number (optional). Applicant is to place a check mark here if English language Translation is attached.

This collection of information is required by 37 CFR 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 120 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the inclividual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alaxandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.